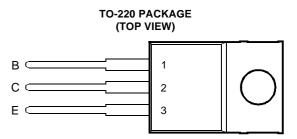
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- Designed for Complementary Use with the TIP31 Series
- 40 W at 25°C Case Temperature
- 3 A Continuous Collector Current
- 5 A Peak Collector Current
- Customer-Specified Selections Available



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	TIP32		-80	
(Collector base veltage (I - 0))	TIP32A	V	-100	V
Collector-base voltage ($I_E = 0$)	TIP32B	V _{CBO}	-120	v
	TIP32C		-140	
	TIP32		-40	
Collector emitter veltere (I)	TIP32A	N	-60	V
Collector-emitter voltage ($I_B = 0$)	TIP32B	V _{CEO}	-80	v
	TIP32C		-100	
Emitter-base voltage	V _{EBO}	-5	V	
Continuous collector current			-3	A
Peak collector current (see Note 1)			-5	A
Continuous base current			-1	А
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			40	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W
Unclamped inductive load energy (see Note 4)			32	mJ
Operating junction temperature range			-65 to +150	°C
Storage temperature range			-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds			250	°C

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%.$

2. Derate linearly to 150°C case temperature at the rate of 0.32 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = -0.4 A, R_{BE} = 100 Ω , $V_{BE(off)}$ = 0, R_S = 0.1 Ω , V_{CC} = -20 V.



Information is current as of publication date. Products conform to specifications in accordance with the terms of Power Innovations standard warranty. Production processing does not necessarily include testing of all parameters.



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electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = -30 mA I _B (see Note 5)		TIP32	-40			
			I _B = 0	TIP32A	-60			V
				TIP32B	-80			
				TIP32C	-100			
	Collector-emitter	V _{CE} = -80 V	$V_{BE} = 0$	TIP32			-0.2	
I		V _{CE} = -100 V	$V_{BE} = 0$	TIP32A	-0.	-0.2	mA	
ICES	cut-off current	V _{CE} = -120 V	$V_{BE} = 0$	TIP32B			-0.2	IIIA
		V _{CE} = -140 V	$V_{BE} = 0$	TIP32C			-0.2	
	Collector cut-off	V _{CE} = -30 V	I _B = 0	TIP32/32A			-0.3	mA
ICEO	current	V _{CE} = -60 V	$I_B = 0$	TIP32B/32C			-0.3	IIIA
I _{EBO}	Emitter cut-off	V _{EB} = -5 V	I _C = 0				-1	mA
'EBO	current		10 = 0				- 1	ШA
h _{FF}	Forward current	$V_{CE} = -4 V$	I _C = -1 A	(see Notes 5 and 6)	25			
"FE	transfer ratio	$V_{CE} = -4 V$	I _C = -3 A		10		50	
V _{CE(sat)}	Collector-emitter	I _B = -375 mA	A I _C = -3 A (see	(see Notes 5 and 6)			-1.2	V
•CE(sat)	saturation voltage	IB = 010 III/						•
V _{BE}	Base-emitter	V _{CE} = -4 V	I _C = -3 A	(see Notes 5 and 6)			-1.8	V
• BE	voltage	VCE - IV					1.0	•
h _{fe}	Small signal forward	$V_{05} = -10 V$	$V_{CE} = -10 V$ $I_{C} = -0.5 A$	f = 1 kHz	20			
''Te	current transfer ratio				20			
h _{fe}	Small signal forward	$V_{CE} = -10 V$ $I_{C} = -0$	I _C = -0.5 A	.5 A f = 1 MHz	3			
	current transfer ratio				Ŭ			

NOTES: 5. These parameters must be measured using pulse techniques, t_p = 300 $\mu s,$ duty cycle \leq 2%.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

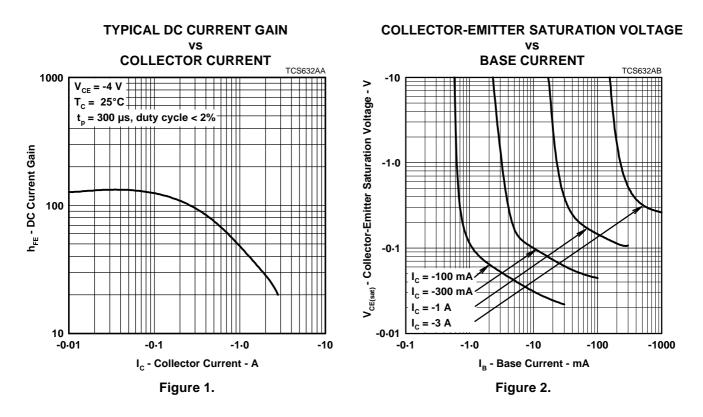
PARAMETER			TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			3.125	°C/W
R_{\thetaJA}	Junction to free air thermal resistance			62.5	°C/W

resistive-load-switching characteristics at 25°C case temperature

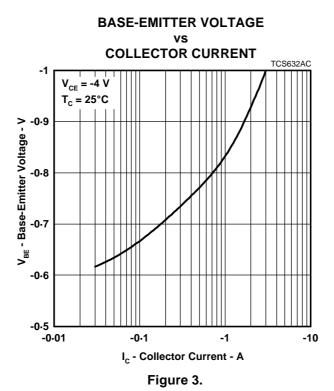
	PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	MAX	UNIT
t _{on}	Turn-on time	I _C = -1 A	I _{B(on)} = -0.1 A	$I_{B(off)} = 0.1 A$		0.3		μs
t _{off}	Turn-off time	$V_{BE(off)} = 4.3 V$	$R_L = 30 \ \Omega$	t_p = 20 µs, dc \leq 2%		1		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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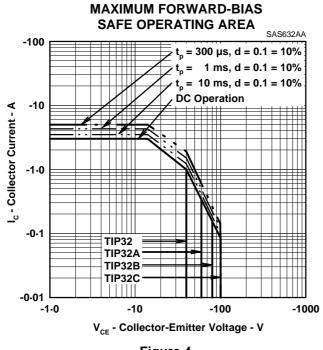


TYPICAL CHARACTERISTICS





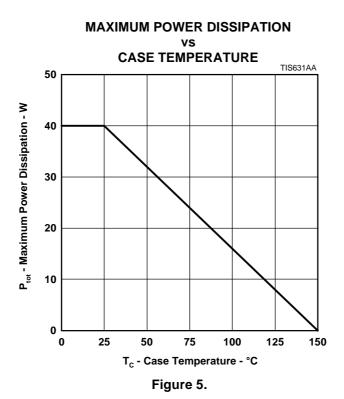
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MAXIMUM SAFE OPERATING REGIONS







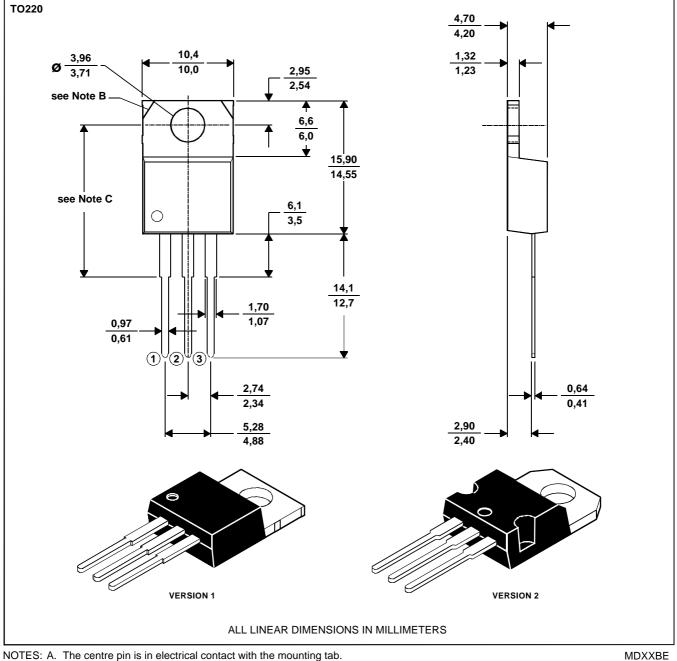
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MECHANICAL DATA

TO-220

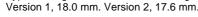
3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



B. Mounting tab corner profile according to package version.

Typical fixing hole centre stand off height according to package version. C.



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